## NSN 5962-01-236-9489

Memory Microcircuit - Page 1 of 1

A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-236-9489

Body Length:	
0.925 inches	
Body Width:	
0.302 inches	
Body Height:	
0.175 inches	
Maximum Pow	er Dissipation Rating:
409.6 milliwatts	
Operating Tem	purature Range:
-55.0/+125.0 de	grees celsius
Storage Tempu	irature Range:
-65.0/+150.0 de	grees celsius
Features Provi	ded:
Hermetically sea	aled and burn in and bipolar and programmable and w/enable
Inclosure Mate	rial:
Ceramic	
Inclosure Conf	iguration:
Dual-in-line	
Output Logic F	orm:
Transistor-trans	istor logic
Input Circuit Pa	attern:
12 input	
Terminal Surfa	ce Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
7.0 volts power	source
Time Rating Pe	er Chacteristic:
60.00 nanosecc	nds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	е Туре:
Rom	
Test Data Docu	Iment:
96906-mil-std-8	83 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type	And Quantity:
18 printed circui	t
Shelf Life:	
N/a	
Unit Of Measur	e:
Demilitarizatio	n:
Yes - demil/mli	
Fiig:	